DATA SHEET =



MB5111GHz HIGH SPEED PRESCALER

HIGH SPEED PRESCALER

The Fujitsu MB511 is a 1.0GHz high speed prescaler that forms a Phase Locked Loop (PLL) circuit when combined with a Fujitsu frequency synthesizer.Based on Fujitsu's advanced Bipolar processing, the MB511 maintains a consistent low power consumption of 23mA @ 5V. In addition, it can detect low amplitude input signals with a sensitivity of –20dBm min.

The MB511 will divide the input frequency a modulus of 1, 2, or 8, and is well suited for applications in CATV and electronically tuned TV.

FEATURES

Wide operating frequency range:
 f_{in} = 50 to 1000MHz (v_{in} = -20dBm)

Maximum operating frequency depends upon a divide ratio:

1/1: 250MHz max. (Buffer through)

1/2: 500MHz max. 1/8: 1000MHz max.

Low supply current: 23mA @5V

High input sensitivity: -20dBm min.

Stable Output Amplitude: 800mVp-p (C_L ≤ 5pF)

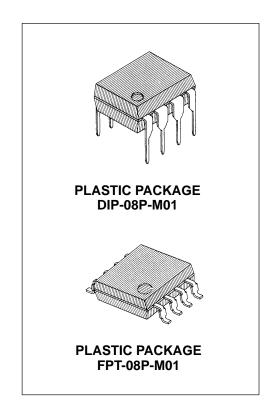
Wide temperature range: T_A = −40 to +85°C

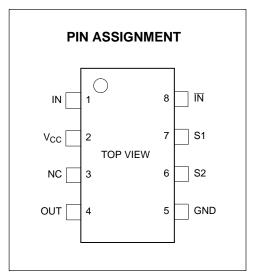
Plastic 8-pin Dual-In-Line package (Suffix: –P)
 Plastic 8-pin Flat package (Suffix: –PF)

ABSOLUTE MAXIMUM RATINGS (See Note)

| Rating | Symbol | Value | Unit |
|----------------------|------------------|------------------------------|------|
| Power Supply Voltage | V _{CC} | -0.5 to +7.0 | V |
| Input Voltage | V _{IN} | -0.5 to V _{CC} +0.5 | V |
| Output Current | Io | 10 | mA |
| Storage Temperature | T _{STG} | -55 to +125 | °C |

Note: Permanent device damage may occur if the above Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

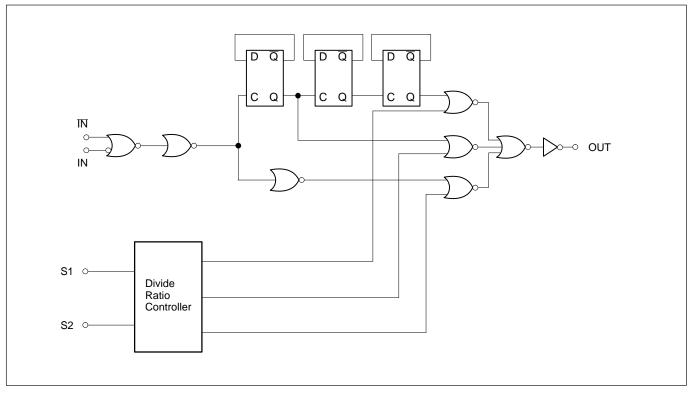


Figure 1. MB511 Block Diagram

FUNCTION TABLE

| S 1 | S2 | Divide Ratio | Operating Frequency | | |
|------------|----|--------------|---------------------|--|--|
| L | L | Not used | _ | | |
| L | Н | 1 | 250MHz | | |
| Н | L | 2 | 500MHz | | |
| Н | Н | 8 | 1000MHz | | |

H = V_{CC} L = OPEN

PIN DESCRIPTIONS

| Pin Number | Symbol | 1/0 | Descriptions | | | |
|------------|-----------------|-----|---|--|--|--|
| 1 | IN | I | Input. The connection with VCO should be an AC connection. | | | |
| 2 | V _{CC} | _ | Power supply voltage input. | | | |
| 3 | NC | _ | No connection. | | | |
| 4 | OUT | 0 | Output. Termination resistor is necessary due to emitter follower output. | | | |
| 5 | GND | _ | Ground. | | | |
| 6 | S2 | I | Divide ratio control input. | | | |
| 7 | S1 | I | Divide ratio control input. | | | |
| 8 | ĪN | I | Complementary Input. | | | |

RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | Value | | | Unit | Note |
|-----------------------|-----------------|-------|------|------|------|----------------------------------|
| | Symbol | Min. | Тур. | Max. | Onit | Note |
| Power Supply Voltage | V _{CC} | 4.5 | 5.0 | 5.5 | V | |
| Operating Temperature | T _A | -40 | | +85 | °C | |
| Load Capacitance | CL | | | 5 | pF | Termination resistor 500Ω |

ELECTRICAL CHARACTERISTICS

| Parameter | | Symbol | Value | | | l lmit | Note |
|--------------------------|--------|-----------------|----------------------|-----------------|----------------------|-----------|---|
| | | Symbol | Min. | Тур. | Max. | Unit | Note |
| Power Supply Current | | I _{CC} | 15 | 23 | 32 | mA | Except termination output current. |
| Output Amplitude | | Vo | 0.4 | 0.8 | 1.2 | V_{p-p} | 500Ω termination, $C_L = 5pF$ max. |
| | 1/1 | f ₁ | 50 | | 250 | MHz | Min. value is measured with coupling capacitor of 1000pF. |
| Input Frequency | 1/2 | f ₂ | 50 | | 500 | MHz | |
| | 1/8 | f ₃ | 50 | | 1000 | MHz | |
| Input Signal Amplitude | | P _{IN} | -20 | | +10 | dBm | 50Ω |
| High Level Input Voltage | S1, S2 | V _{IH} | V _{CC} -0.7 | V _{CC} | V _{CC} +0.5 | V | |
| Low Level Input Voltage | 31, 32 | V _{IL} | | OPEN | | V | |
| Low Level Input Current | S1, S2 | I _{IH} | 40 | | 160 | μΑ | V _{CC} = 5V |

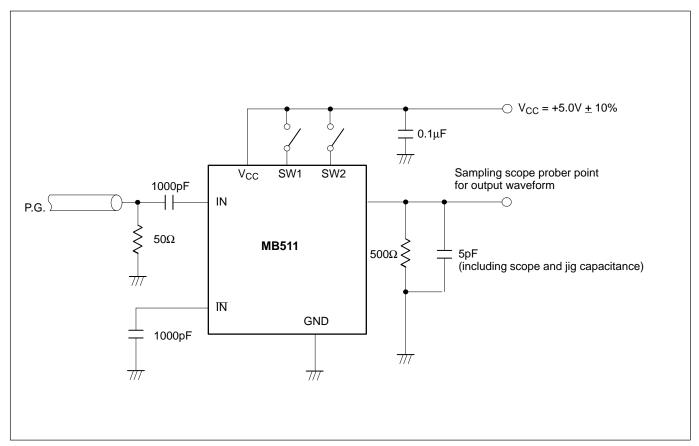
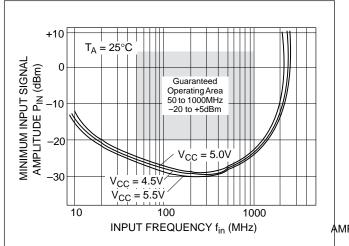


Figure 2. Test Circuit

TYPICAL CHARACTERISTICS CURVES





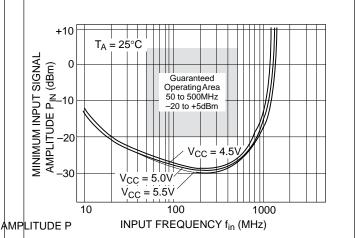


Figure 4. Input Sensitivity Curve (1/2 Divide Ratio)
Power Supply Voltage Dependency

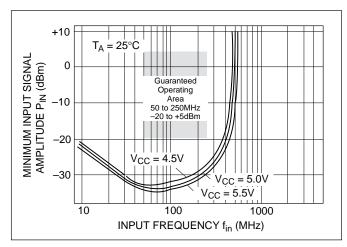


Figure 5. Input Sensitivity Curve (1/1 Divide Ratio)
Power Supply Voltage Dependency

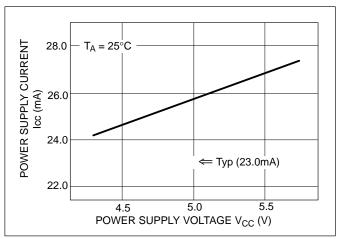


Figure 6. Power Supply Current vs. Power Supply Voltage

TYPICAL CHARACTERISTICS CURVES (Continued)

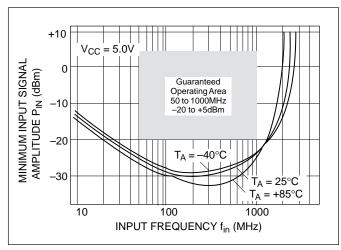


Figure 7. Input Sensitivity Curve (1/8 Divide Ratio)
Temperature Dependency

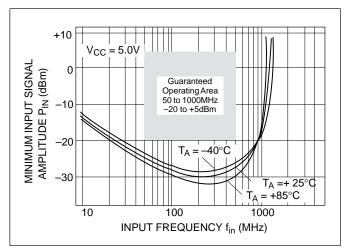


Figure 6. Input Sensitivity Curve (1/2 Divide Ratio)
Temperature Dependency

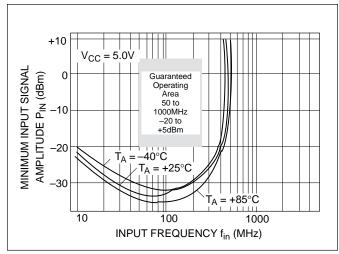


Figure 9. Input Sensitivity Curve (1/1 Divide Ratio)
Temperature Dependency

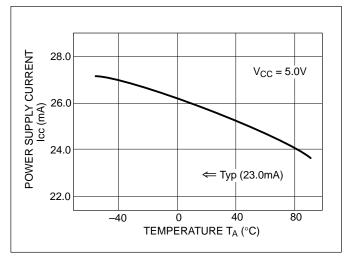
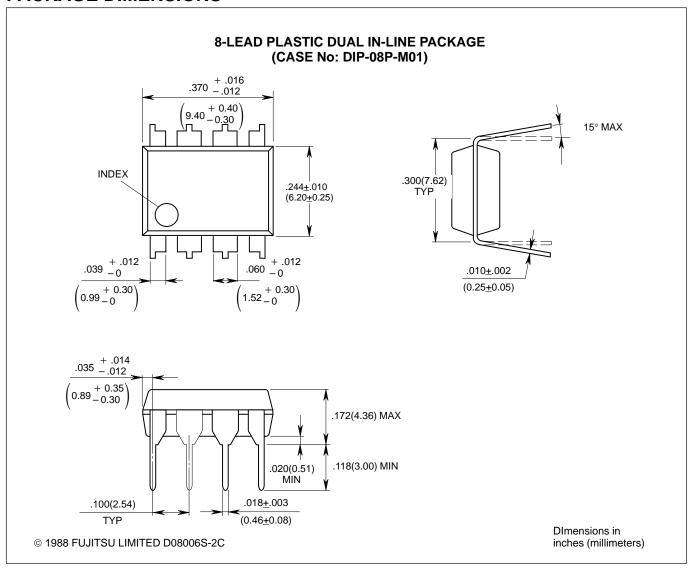
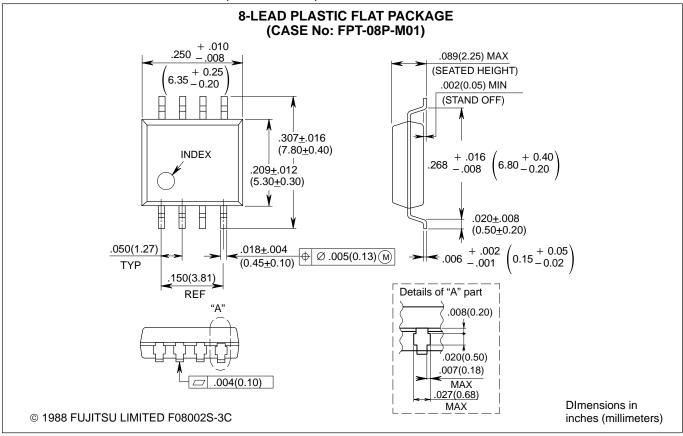


Figure 10. Power Supply Current vs. Temperature

PACKAGE DIMENSIONS



PACKAGE DIMENSIONS (Continued)



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